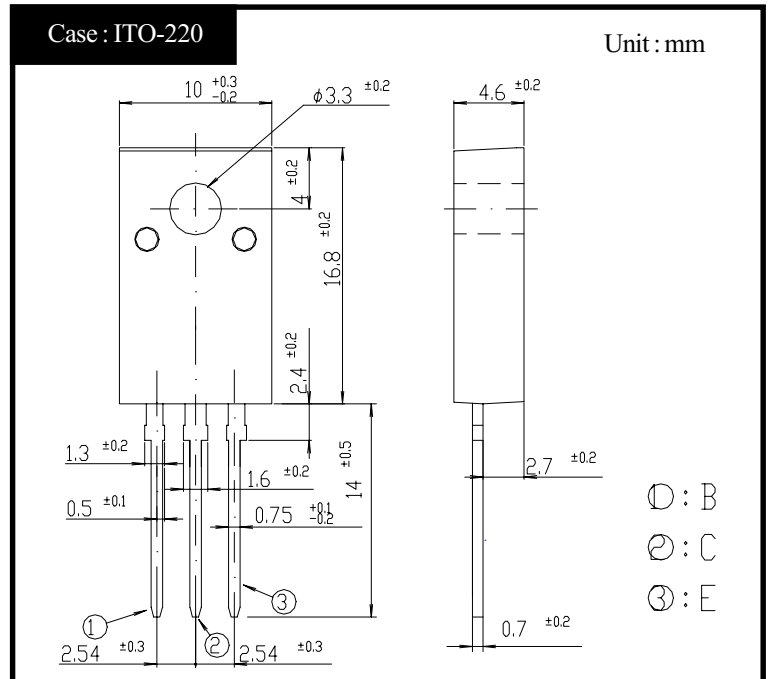


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(TP8V20FS)

8A NPN

OUTLINE DIMENSIONS



RATINGS

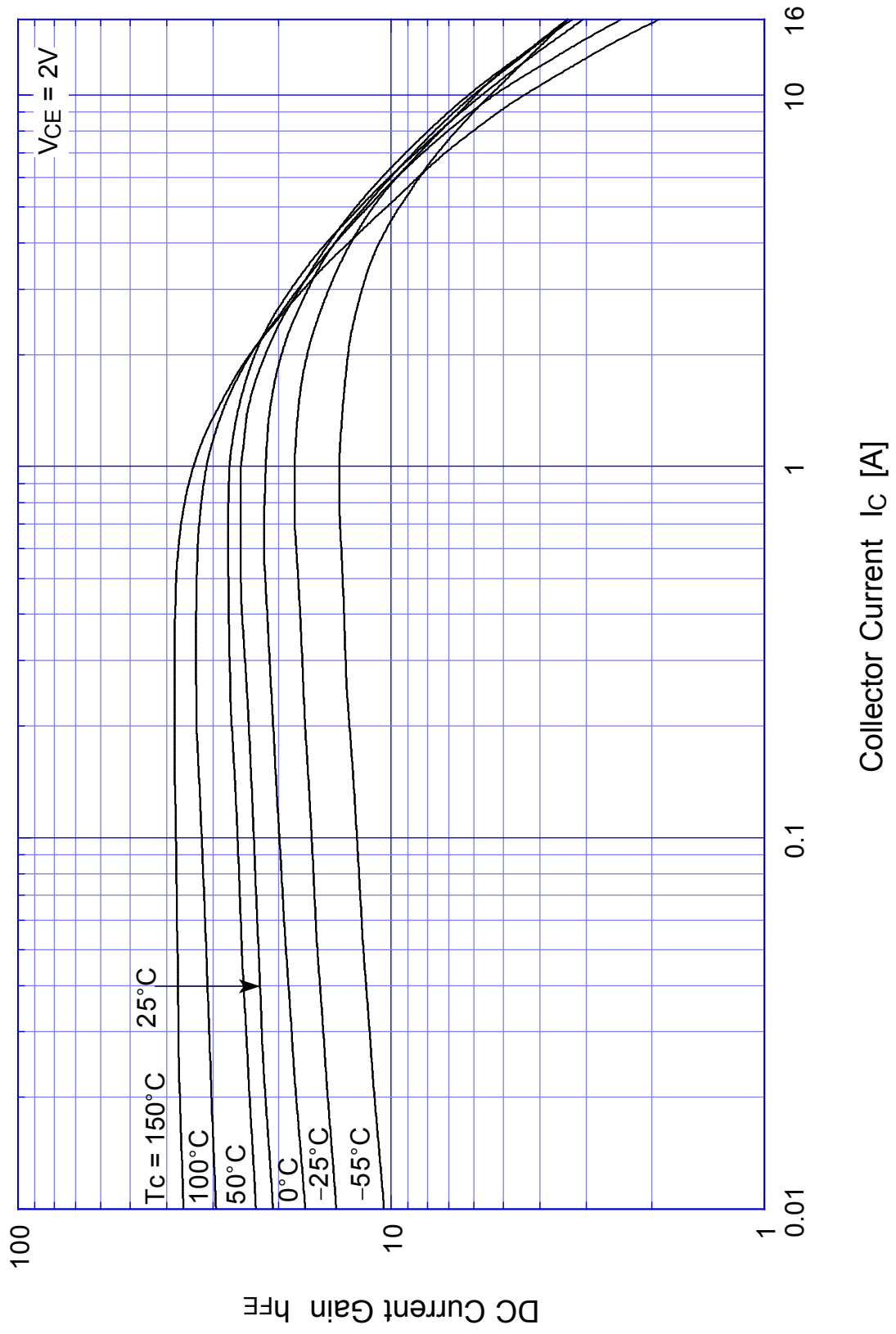
● Absolute Maximum Ratings

Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	T_{stg}		-55~150	°C
Junction Temperature	T_j		150	°C
Collector to Base Voltage	V_{CBO}		250	V
Collector to Emitter Voltage	V_{CEO}		200	V
Emitter to Base Voltage	V_{EBO}		7	V
Collector Current DC	I_C		8	A
Collector Current Peak	I_{CP}		16	
Base Current DC	I_B		3	A
Base Current Peak	I_{BP}		6	
Total Transistor Dissipation	P_T	$T_c = 25^\circ\text{C}$	30	W
Dielectric Strength	V_{dis}	Terminals to case, AC 1 minute	2	kV
Mounting Torque	TOR	(Recommended torque : 0.3N·m)	0.5	N·m

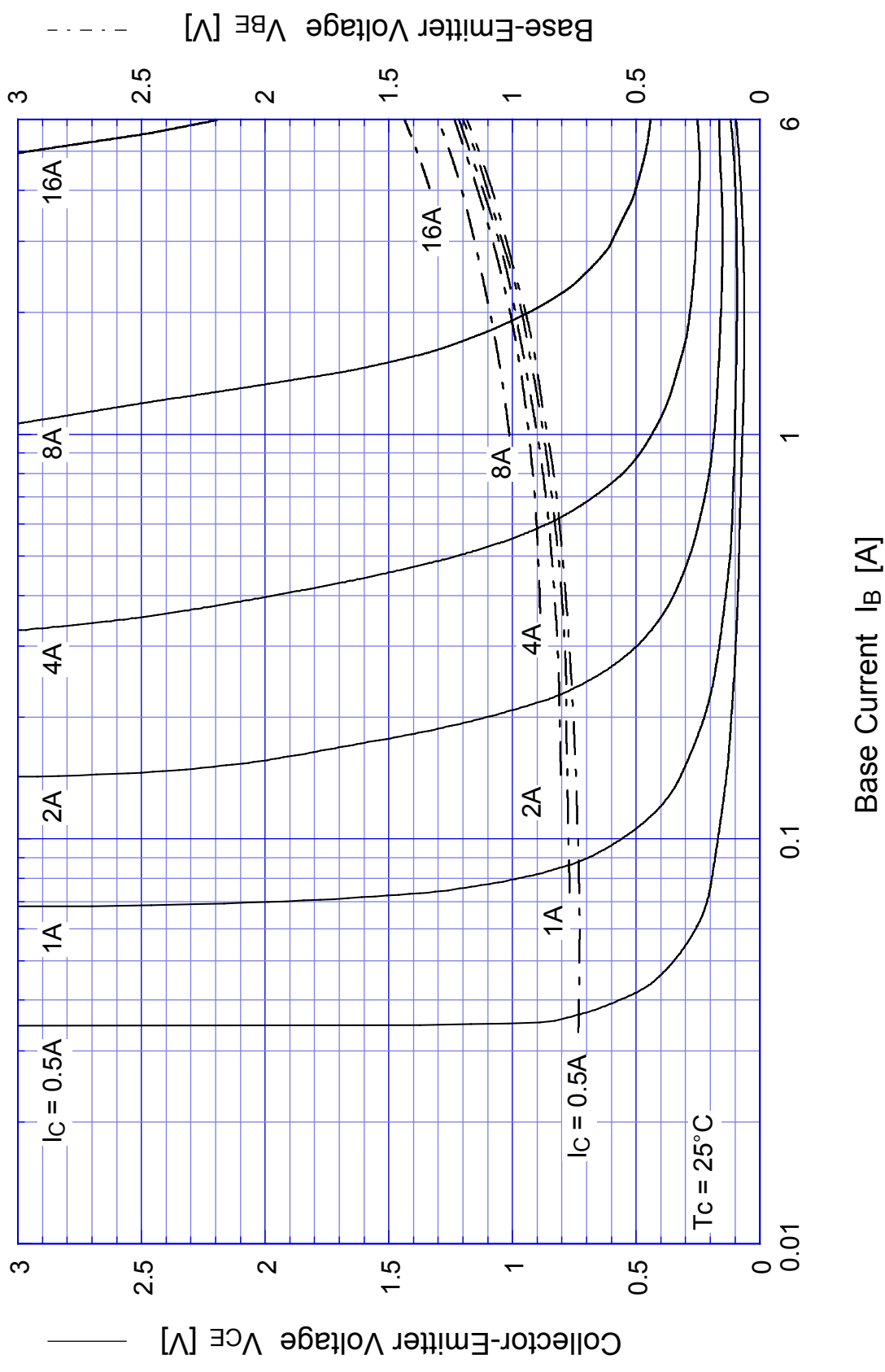
● Electrical Characteristics ($T_c=25^\circ\text{C}$)

Item	Symbol	Conditions	Ratings	Unit
Collector to Emitter Sustaining Voltage	$V_{CEO(sus)}$	$I_C = 0.1\text{A}$	Min 200	V
Collector Cutoff Current	I_{CBO}	At rated Voltage	Max 0.1	mA
	I_{CEO}		Max 0.1	
Emitter Cutoff Current	I_{EBO}	At rated Voltage	Max 0.1	mA
DC Current Gain	h_{FE}	$V_{CE} = 2\text{V}, I_C = 4\text{A}$	10~25 ^{*1}	
	h_{FEL}	$V_{CE} = 2\text{V}, I_C = 1\text{mA}$	Min 10	
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 4\text{A}$	Max 1.0	V
Base to Emitter Saturation Voltage	$V_{BE(sat)}$	$I_B = 0.8\text{A}$	Max 1.5	V
Thermal Resistance	θ_{jc}	Junction to case	Max 4.17	°C/W
Transition Frequency	f_T	$V_{CE} = 10\text{V}, I_C = 0.8\text{A}$	TYP 13	MHz
Turn on Time	t_{on}	$I_C = 4\text{A}$ $I_{B1} = 0.8\text{A}, I_{B2} = 1.6\text{A}$ $R_L = 37.5\ \Omega, V_{BB2} = 4\text{V}$	Max 0.3	μs
Storage Time	t_s		Max 1.0	
Fall Time	t_f		Max 0.1	

2SC4664 $h_{FE} - I_c$

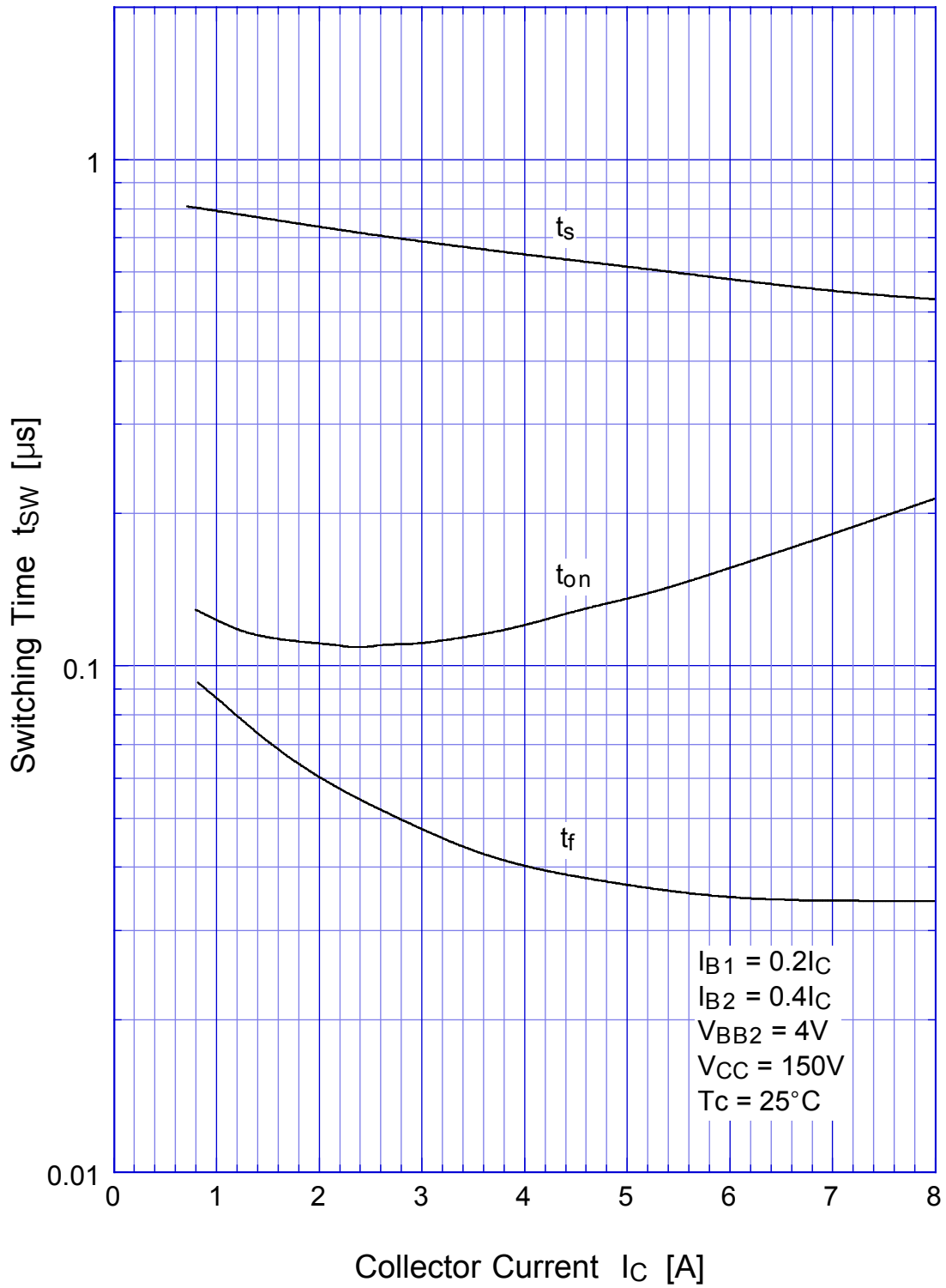


2SC4664 Saturation Voltage



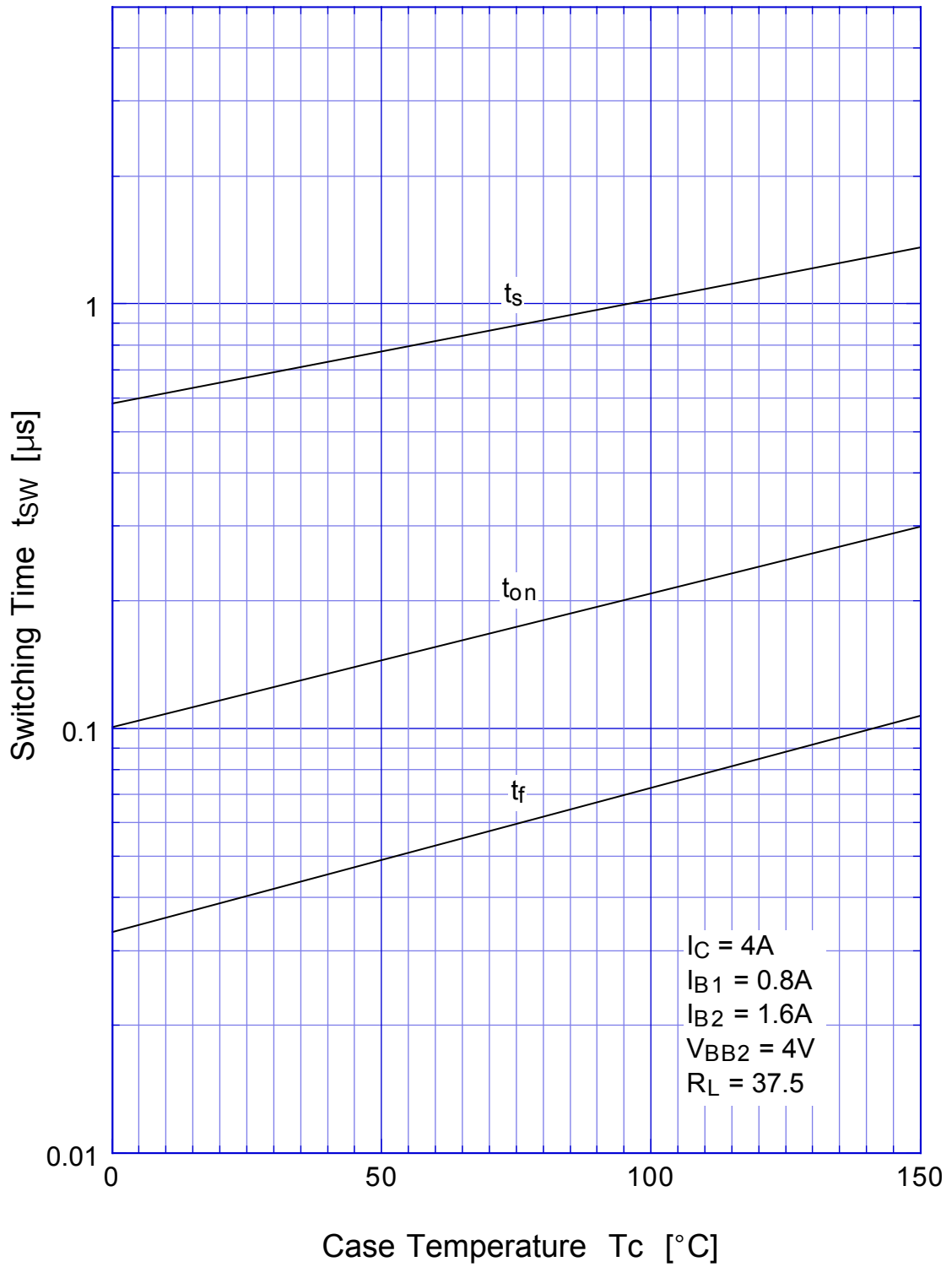
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Switching Time - I_C



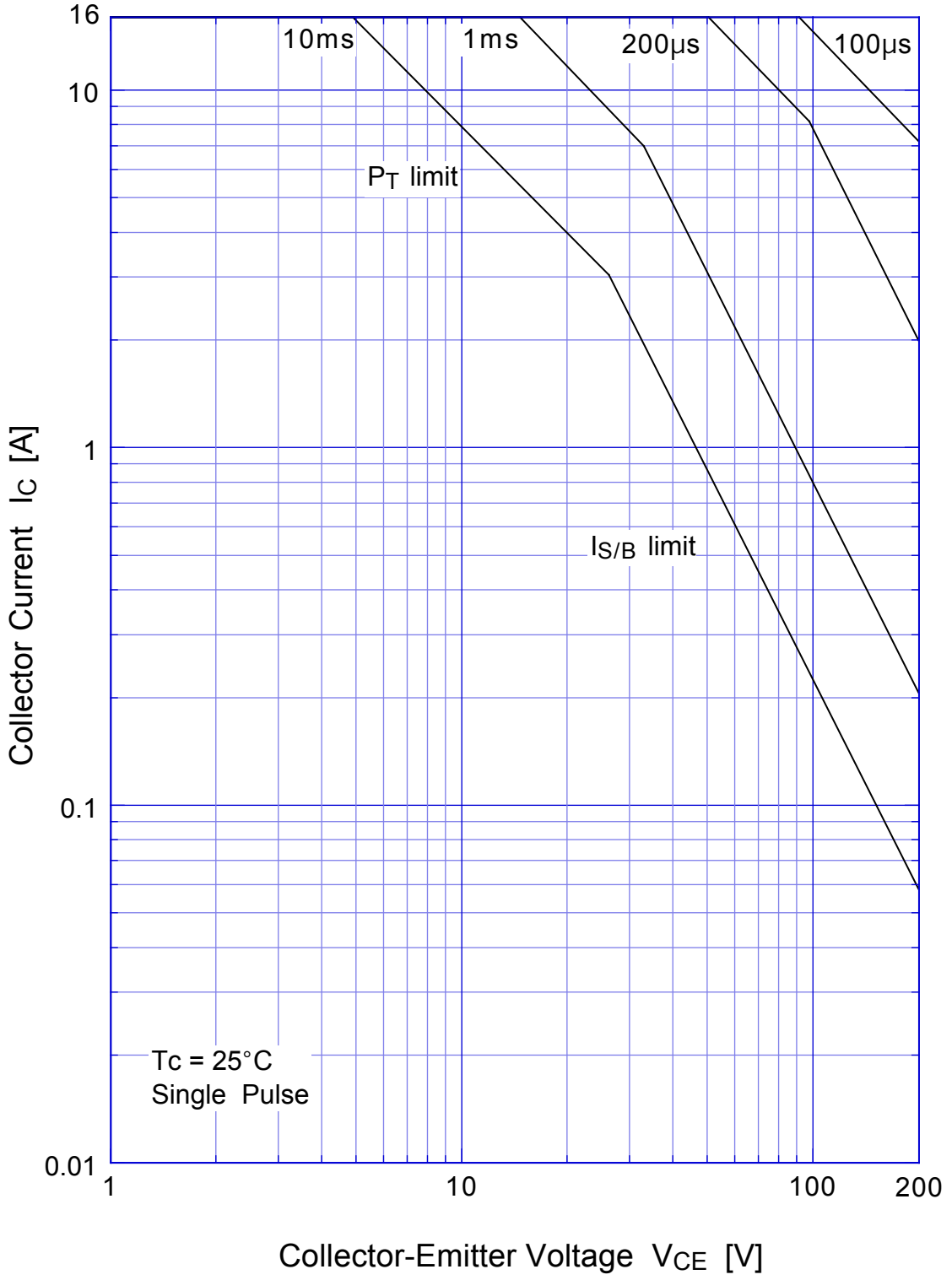
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Switching Time - Tc

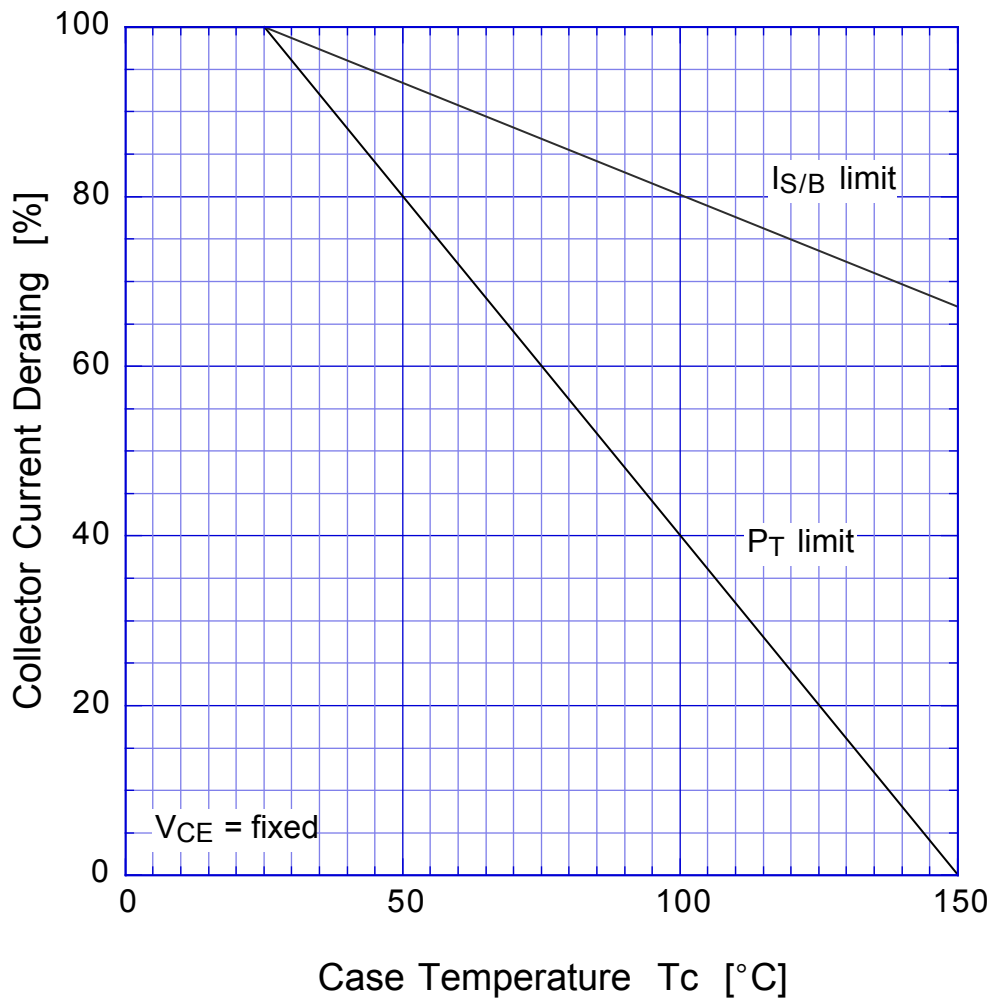


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Forward Bias SOA

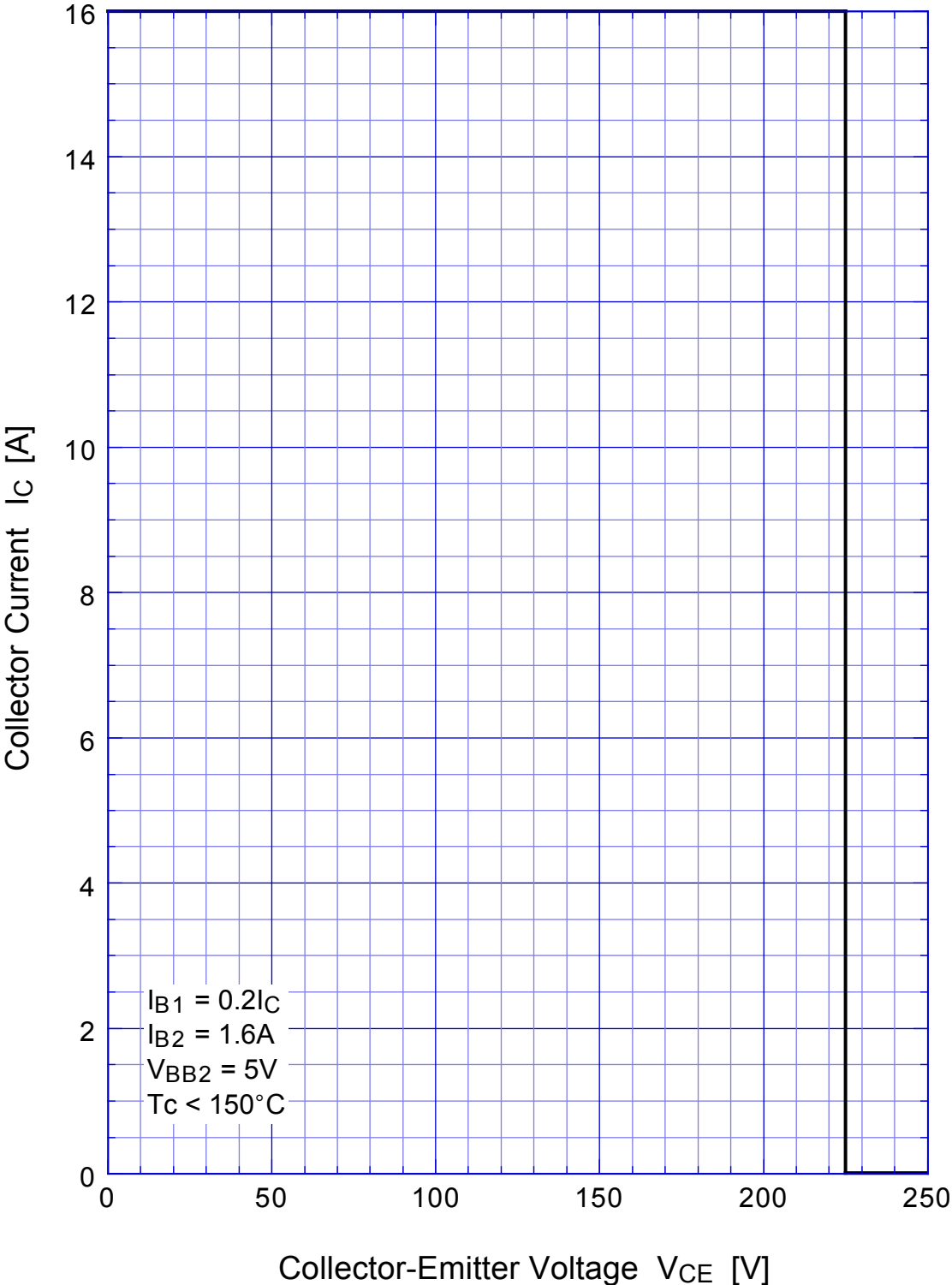


2SC4664 Collector Current Derating



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Reverse Bias SOA



2SC4664 Transient Thermal Impedance

